

RT5P227C

Transistor With Resistor
For Switching Application
Silicon PNP Epitaxial Type

DESCRIPTION

RT5P227C is a one chip transistor with built-in bias resistor.

FEATURE

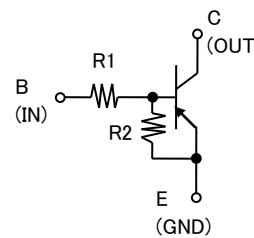
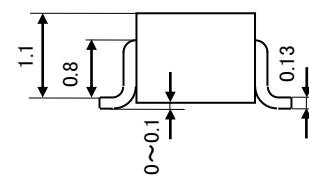
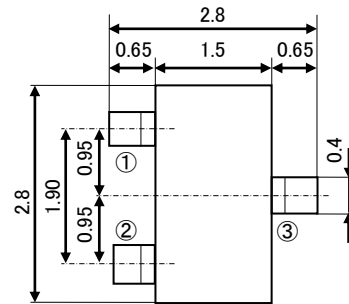
Built-in bias resistor ($R_1=0.22k\Omega$, $R_2=4.7k\Omega$)
High collector current ($I_C=-0.5A$)
Mini package for easy mounting

APPLICATION

Inverted circuit, Switching circuit, Interface circuit,
Driver circuit

OUTLINE DRAWING

Unit: mm



JEITA: SC-59

JEDEC: Similar to TO-236

Terminal Connector

①: BASE

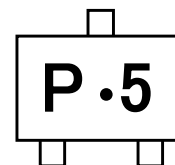
②: EMITTER

③: COLLECTOR

MAXIMUM RATING ($T_a=25^\circ\text{C}$)

| SYMBOL | PARAMETER | RATING | UNIT |
|-----------|---|----------|------------------|
| V_{CBO} | Collector to Base voltage | -50 | V |
| V_{EBO} | Emitter to Base voltage | -5 | V |
| V_{CEO} | Collector to Emitter voltage | -50 | V |
| V_{IN} | Input voltage | -5 | V |
| I_C | Collector current | -500 | mA |
| P_C | Collector dissipation($T_a=25^\circ\text{C}$) | 200 | mW |
| T_j | Junction temperature | +150 | $^\circ\text{C}$ |
| T_{stg} | Storage temperature | -55~+150 | $^\circ\text{C}$ |

MARKING



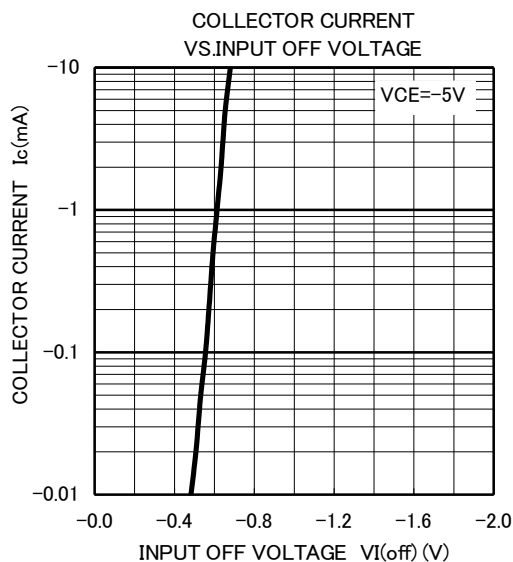
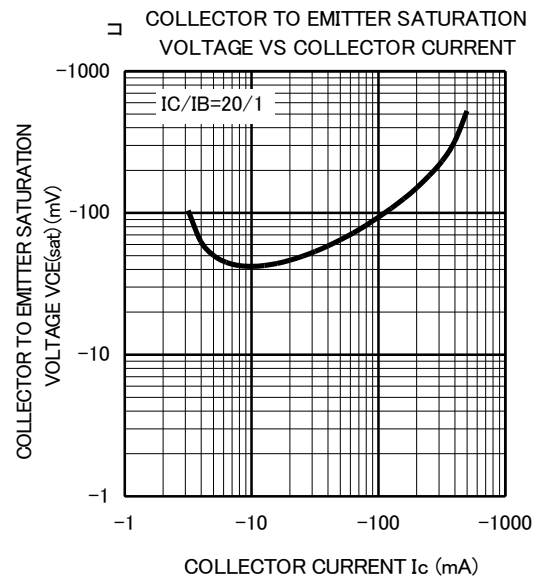
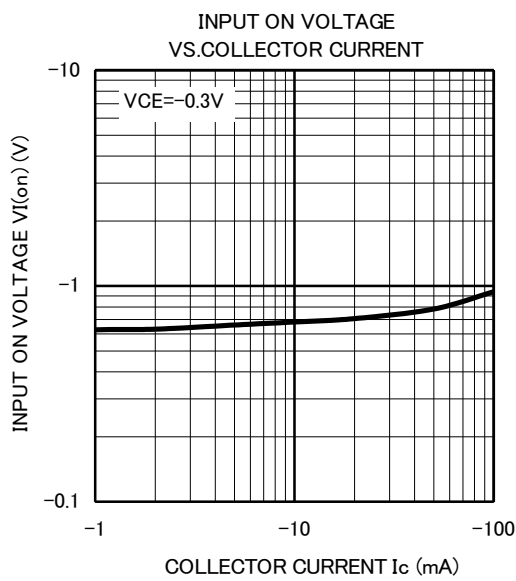
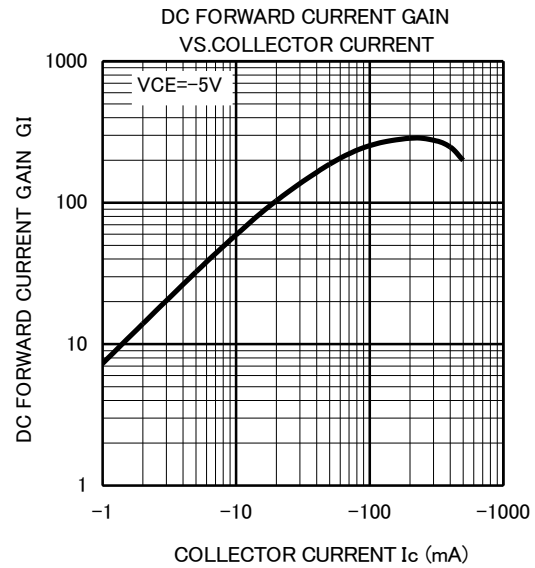
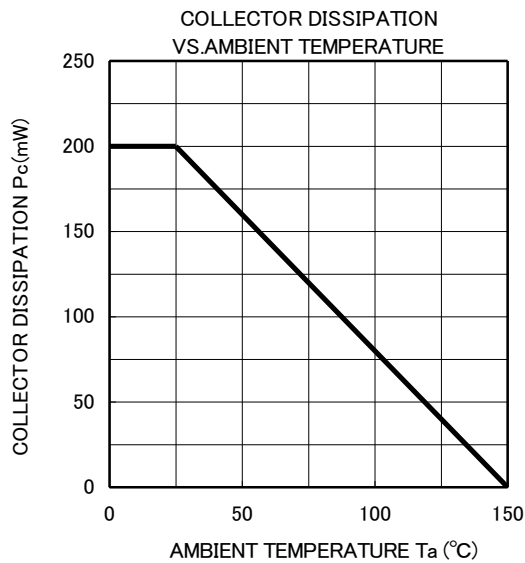
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

| SYMBOL | PARAMETER | TEST CONDITION | LIMIT | | | UNIT |
|---------------|---------------------------|--|-------|------|-------|-----------|
| | | | MIN | TYP | MAX | |
| $V_{I(on)}$ | Input on voltage | $V_{CE}=-0.3V$, $I_C=-30mA$ | — | — | -2 | V |
| $V_{I(off)}$ | Input off voltage | $V_{CE}=-5V$, $I_C=-100\mu A$ | -0.5 | — | — | V |
| $V_{CE(sat)}$ | C to E saturation voltage | $I_C=-50mA$, $I_B=-2.5mA$ | — | -0.1 | -0.3 | V |
| I_{BE} | B to E current | $V_{BE}=-5V$ | — | — | -45 | mA |
| I_{CES} | Collector cut off current | $V_{CE}=-50V$, $V_{BE}=0V$ | — | — | -0.5 | μA |
| G_1 | DC forward current gain | $V_{CE}=-5V$, $I_C=-50mA$ | 47 | — | — | — |
| R_1 | Input resistor | — | 0.154 | 0.22 | 0.286 | $k\Omega$ |
| R_2/R_1 | Resistor ratio | — | 17.1 | 21.3 | 25.6 | — |
| f_T | Gain band width product | $V_{CE}=-10V$, $I_E=5mA$, $f=100MHz$ | — | 150 | — | MHz |

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TYPICAL CHARACTERISTICS



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